

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,709,610 B2
APPLICATION NO. : 09/768494
DATED : March 23, 2004
INVENTOR(S) : Peter C. Van Buskirk et al.

Page 1 of 1

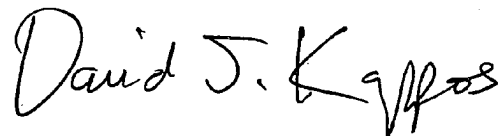
It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 1, line 16: "mance of U.S. Government Contract No. DAA HOI 96-C-" should be
-- mance of U.S. Government Contract No. DAAH01-96-C- --.

Column 1, line 17: "RD35, "BaSrTiO 3 Etching for Advanced Microelectronic" should be
-- R035, "BaSrTiO 3 Etching for Advanced Microelectronic --.

Signed and Sealed this

Second Day of November, 2010

A handwritten signature in black ink, reading "David J. Kappos". The signature is written in a cursive, flowing style with a large, stylized 'D' and 'K'.

David J. Kappos
Director of the United States Patent and Trademark Office